

N-Channel Power MOSFET

60V, 70A, 12mΩ

FEATURES

- Low $R_{DS(ON)}$ to minimize conductive losses
- Logic level
- Low gate charge for fast power switching
- 100% UIS and R_g tested
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

KEY PERFORMANCE PARAMETERS

PARAMETER	VALUE	UNIT
V_{DS}	60	V
$R_{DS(on)}$ (max)	12	mΩ
	15	
Q_g	18	nC

APPLICATIONS

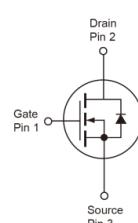
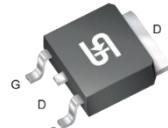
- BLDC Motor Control
- Battery Power Management
- Secondary Synchronous Rectification



ROHS
COMPLIANT

HALOGEN
FREE

TO-252(DPAK)



Notes: MSL 3 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current $T_C = 25^\circ\text{C}$	I_D	70	A
$T_A = 25^\circ\text{C}$		10	
Pulsed Drain Current ^(Note 1)	I_{DM}	280	A
Single Pulse Avalanche Current ^(Note 2)	I_{AS}	20	A
Single Pulse Avalanche Energy ^(Note 2)	E_{AS}	60	mJ
Total Power Dissipation $T_C = 25^\circ\text{C}$	P_D	125	W
$T_C = 125^\circ\text{C}$		25	
Total Power Dissipation $T_A = 25^\circ\text{C}$	P_D	2.6	W
$T_A = 125^\circ\text{C}$		0.5	
Operating Junction and Storage Temperature Range	T_J, T_{STG}	- 55 to +150	°C

THERMAL PERFORMANCE

PARAMETER	SYMBOL	LIMIT	UNIT
Junction to Case Thermal Resistance	$R_{\Theta JC}$	1	°C/W
Junction to Ambient Thermal Resistance	$R_{\Theta JA}$	49	°C/W

Thermal Performance Note: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design.

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{V}$, $I_D = 250\mu\text{A}$	BV_{DSS}	60	--	--	V
Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250\mu\text{A}$	$V_{GS(\text{TH})}$	1.2	1.7	2.5	V
Gate-Source Leakage Current	$V_{GS} = \pm 20\text{V}$, $V_{DS} = 0\text{V}$	I_{GSS}	--	--	± 100	nA
Drain-Source Leakage Current	$V_{GS} = 0\text{V}$, $V_{DS} = 60\text{V}$	I_{DSS}	--	--	1	μA
	$V_{GS} = 0\text{V}$, $V_{DS} = 60\text{V}$ $T_J = 125^\circ\text{C}$		--	--	100	
Drain-Source On-State Resistance (Note 3)	$V_{GS} = 10\text{V}$, $I_D = 10\text{A}$	$R_{DS(\text{on})}$	--	9.7	12	$\text{m}\Omega$
	$V_{GS} = 4.5\text{V}$, $I_D = 10\text{A}$		--	11	15	
Forward Transconductance ^(Note 3)	$V_{DS} = 5\text{V}$, $I_D = 10\text{A}$	g_{fs}	--	40	--	S
Dynamic ^(Note 4)						
Total Gate Charge	$V_{GS} = 10\text{V}$, $V_{DS} = 30\text{V}$, $I_D = 10\text{A}$	Q_g	--	37	--	nC
Total Gate Charge	$V_{GS} = 4.5\text{V}$, $V_{DS} = 30\text{V}$, $I_D = 10\text{A}$	Q_g	--	18	--	
Gate-Source Charge		Q_{gs}	--	6	--	
Gate-Drain Charge		Q_{gd}	--	7.5	--	
Input Capacitance	$V_{GS} = 0\text{V}$, $V_{DS} = 30\text{V}$ $f = 1.0\text{MHz}$	C_{iss}	--	2118	--	pF
Output Capacitance		C_{oss}	--	136	--	
Reverse Transfer Capacitance		C_{rss}	--	86	--	
Gate Resistance	$f = 1.0\text{MHz}$, open drain	R_g	0.5	1.6	3.2	Ω
Switching ^(Note 4)						
Turn-On Delay Time	$V_{GS} = 10\text{V}$, $V_{DS} = 30\text{V}$, $I_D = 10\text{A}$, $R_G = 2\Omega$,	$t_{d(on)}$	--	6.4	--	ns
Turn-On Rise Time		t_r	--	13.4	--	
Turn-Off Delay Time		$t_{d(off)}$	--	25.6	--	
Turn-Off Fall Time		t_f	--	6.6	--	
Source-Drain Diode						
Forward Voltage ^(Note 3)	$V_{GS} = 0\text{V}$, $I_S = 10\text{A}$	V_{SD}	--	--	1	V
Reverse Recovery Time	$I_S = 10\text{A}$, $dI/dt = 100\text{A}/\mu\text{s}$	t_{rr}	--	17	--	ns
Reverse Recovery Charge		Q_{rr}	--	13	--	nC

Notes:

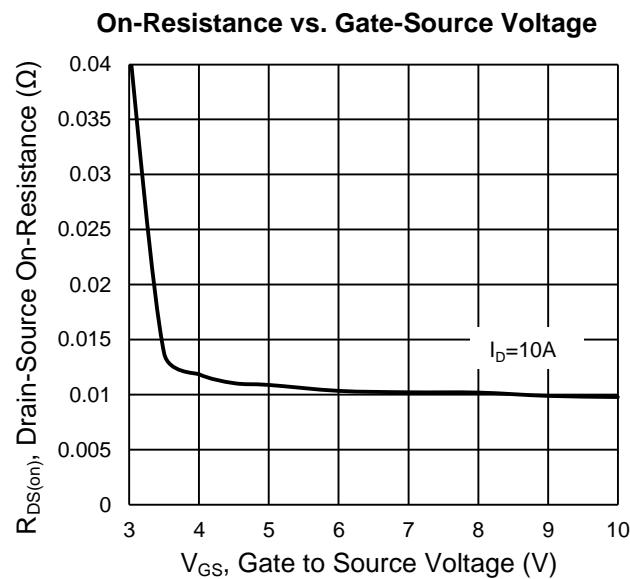
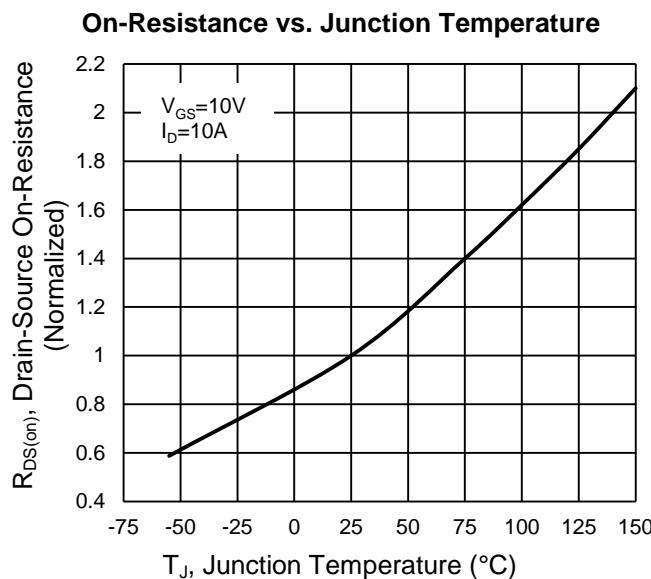
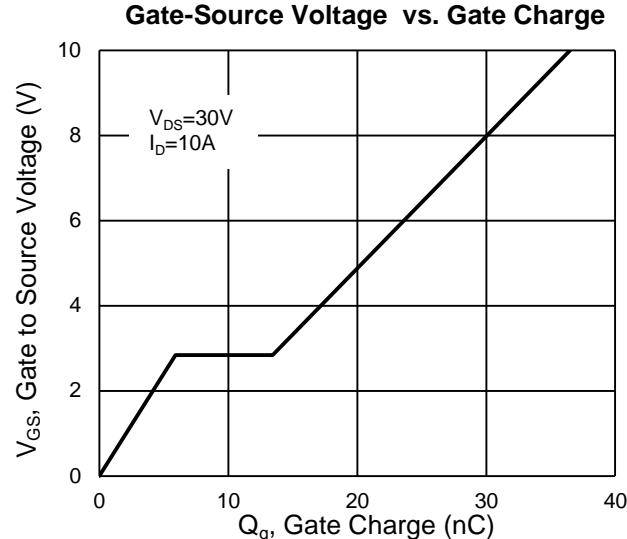
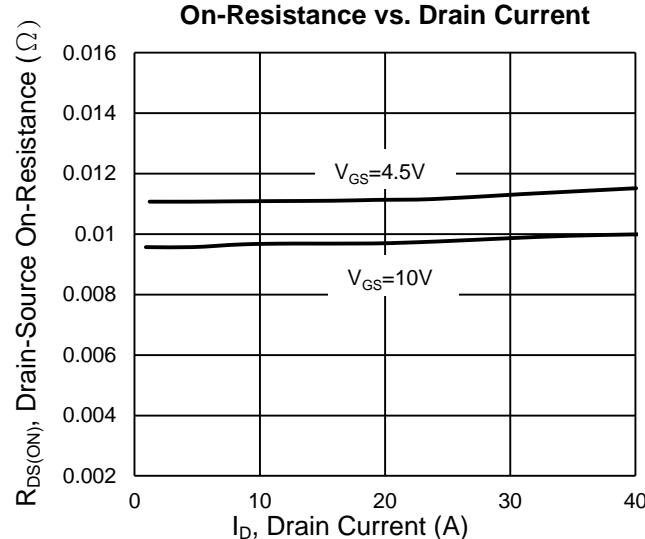
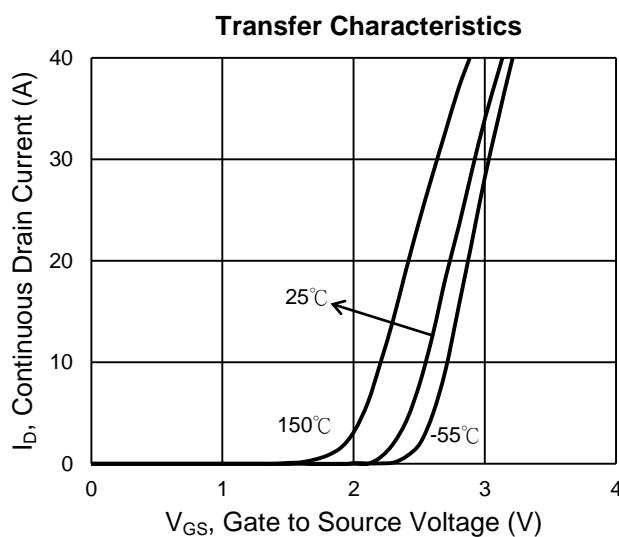
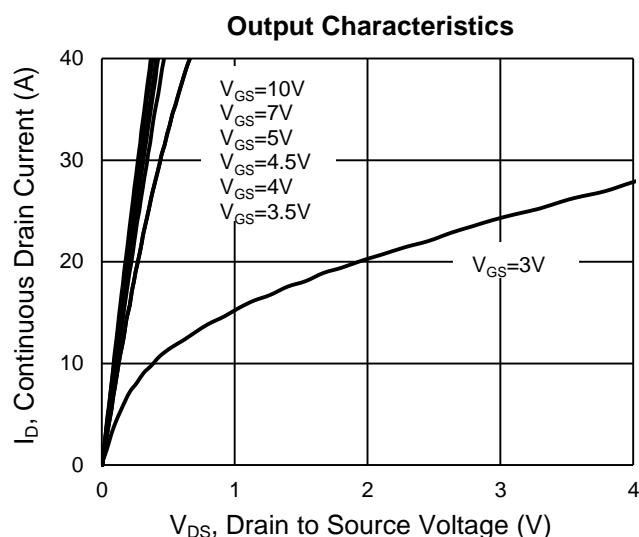
1. Current limited by package.
2. $L = 0.3\text{mH}$, $V_{GS} = 10\text{V}$, $V_{DD} = 30\text{V}$, $R_G = 25\Omega$, $I_{AS} = 20\text{A}$, Starting $T_J = 25^\circ\text{C}$
3. Pulse test: Pulse Width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.
4. Switching time is essentially independent of operating temperature.

ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM120N06LCP ROG	TO-252(DPAK)	2,500pcs / 13" Reel

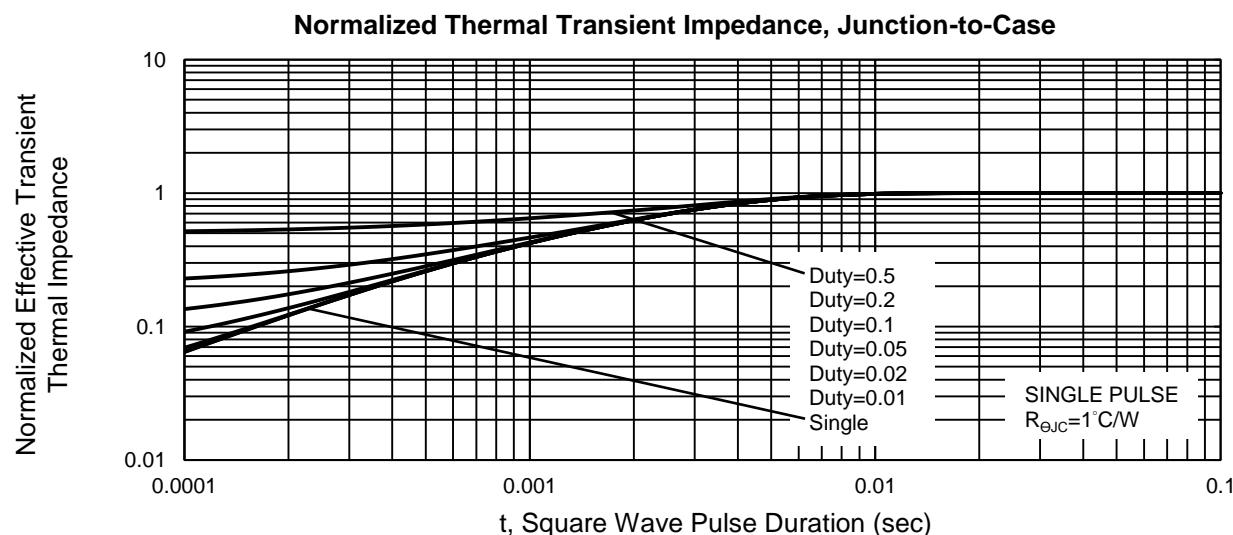
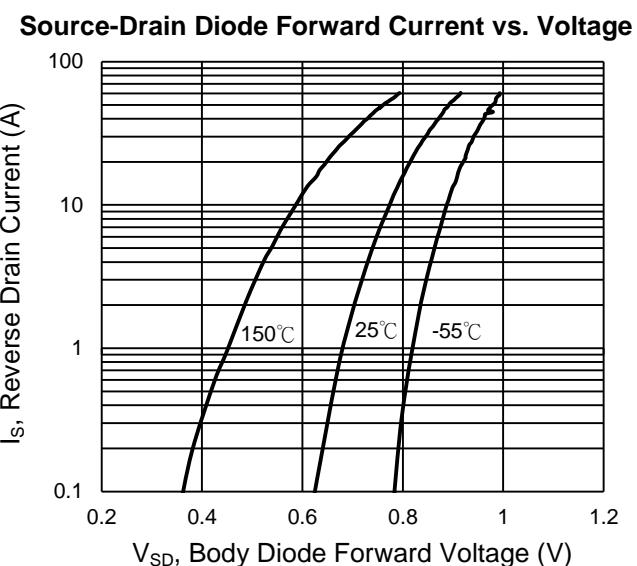
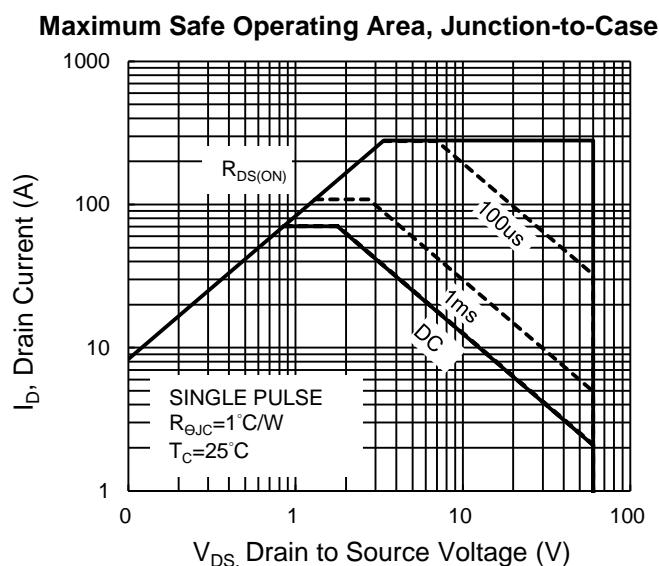
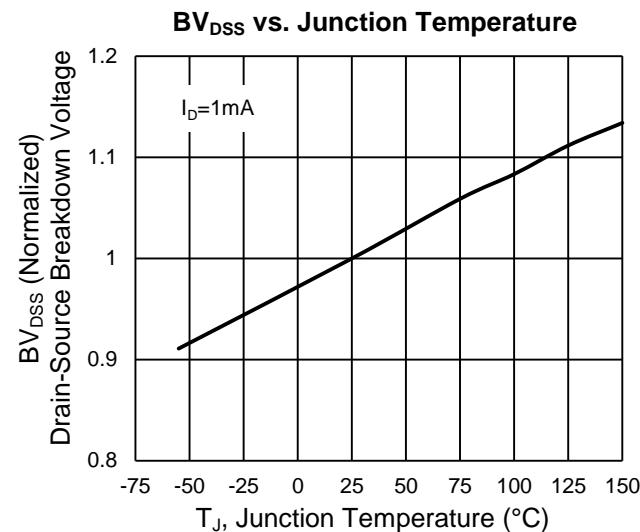
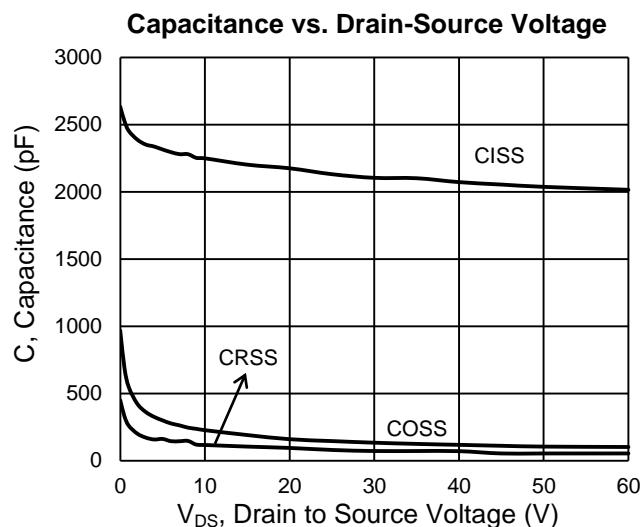
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

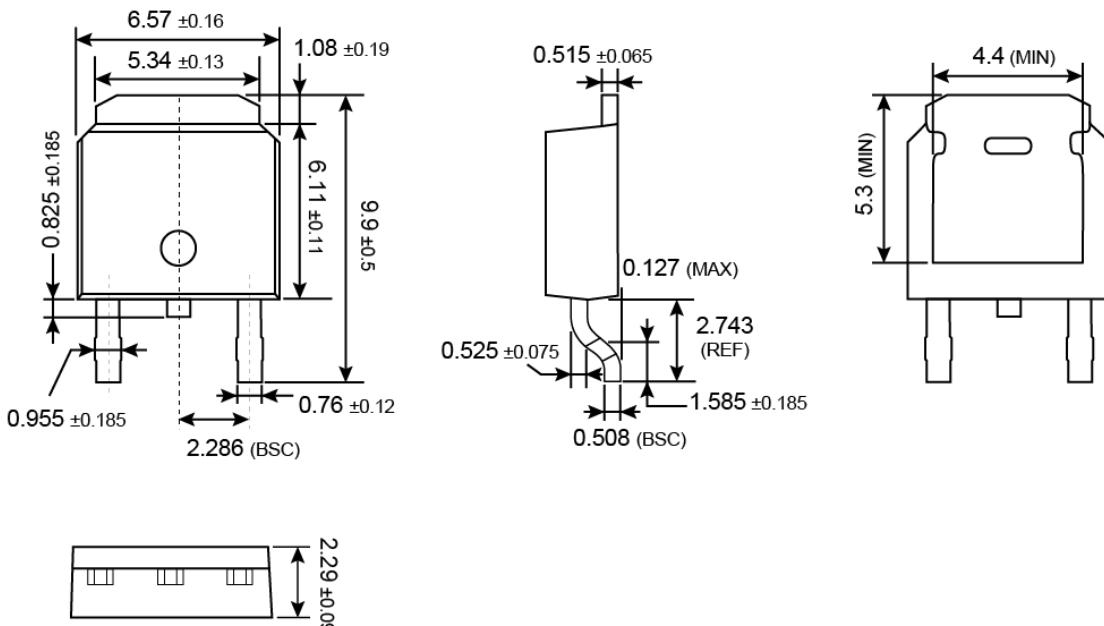
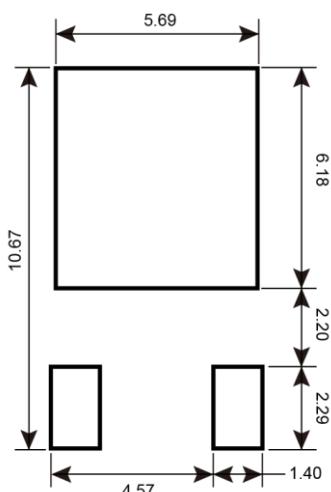


CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

TO-252(DPAK)

SUGGESTED PAD LAYOUT (Unit: Millimeters)

MARKING DIAGRAM

Y = Year Code

M = Month Code for Halogen Free Product

O =Jan **P** =Feb **Q** =Mar **R** =Apr

S =May **T** =Jun **U** =Jul **V** =Aug

W =Sep **X** =Oct **Y** =Nov **Z** =Dec

L = Lot Code (1~9, A~Z)

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